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September 2001



FDC6420C

20V N & P-Channel PowerTrench® MOSFETs

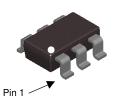
General Description

These N & P-Channel MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive SO-8 and TSSOP-8 packages are impractical.

Applications

- DC/DC converter
- Load switch
- LCD display inverter



SuperSOT™-6

Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter		Q1	Q2	Units
V _{DSS}	Drain-Source Voltage		20	-20	V
V _{GSS}	Gate-Source Voltage		±12	±12	V
ID	Drain Current – Continuous	(Note 1a)	3.0	-2.2	Α
	– Pulsed		12	6	
PD	Power Dissipation for Single Operation	(Note 1a)	0.96		
		(Note 1b)	0	.9	W
		(Note 1c)	0	.7	
T _J , T _{STG}	Operating and Storage Junction Temperatu	ire Range	–55 to	°C	
Therma	I Characteristics				
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	1:	30	°C/W
R _{0JC}	Thermal Resistance, Junction-to-Case	(Note 1)	60		°C/W

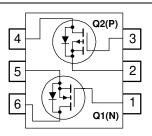
Package Marking and Ordering Information

.420 FDC6420C 7" 8mm 3000 units	Device Marking	Device	Reel Size	Tape width	Quantity
	.420	FDC6420C	7"	8mm	3000 units

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Features

- Q1 3.0 A, 20V. $R_{DS(ON)} = 70 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$ $R_{DS(ON)} = 95 \text{ m}\Omega @ V_{GS} = 2.5 \text{ V}$
- Q2 –2.2 A, 20V. $R_{DS(ON)}$ = 125 m Ω @ V_{GS} = –4.5 V $R_{DS(ON)}$ = 190 m Ω @ V_{GS} = –2.5 V
- Low gate charge
- High performance trench technology for extremely low R_{DS(ON)}.
- SuperSOT –6 package: small footprint (72% smaller than SO-8); low profile (1mm thick).



Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted Symbol Min Max Units Parameter **Test Conditions** Тур **Off Characteristics** 20 $V_{GS} = 0 V$, $I_{D} = 250 \ \mu A$ Q1 ٧ $\mathsf{BV}_{\mathsf{DSS}}$ Drain-Source Breakdown Voltage $V_{GS} = 0 V$, $I_{D} = -250 \ \mu A$ Q2 -20 $I_D = 250 \ \mu A$, Ref. to $25^{\circ}C$ ΔBV_{DSS} Breakdown Voltage Temperature Q1 13 mV/°C Coefficient $I_D = -250 \ \mu A$, Ref. to $25^{\circ}C$ Q2 -11 $\Delta T_{\rm J}$ $V_{DS} = 16 V$, $V_{GS} = 0 V$ Q1 1 Zero Gate Voltage Drain Current μΑ IDSS $V_{DS} = -16 V$, $V_{GS} = 0 V$ Q2 -1 Q1 100 I_{GSSF} Gate-Body Leakage, Forward nA Q2 100 $V_{GS} = -12 \text{ V}, \quad V_{DS} = 0 \text{ V}$ -100 Q1 Gate-Body Leakage, Reverse nA IGSSR $V_{GS} = -12 V$, $V_{DS} = 0 V$ Q2 -100 On Characteristics (Note 2) Gate Threshold Voltage $V_{\text{DS}} = V_{\text{GS}}, \, I_{\text{D}} = 250 \; \mu \text{A}$ 0.5 0.9 V $V_{\text{GS(th)}}$ Q1 1.5 Q2 $V_{DS} = V_{GS}, I_D = -250 \ \mu A$ -0.6 -1.0 -1.5 $\Delta V_{GS(th)}$ Gate Threshold Voltage mV/°C Q1 $I_D = 250 \ \mu A$, Ref. To $25^{\circ}C$ -3 **Temperature Coefficient** ΔT_{\perp} $I_D = -250 \ \mu A$, Ref. to $25^{\circ}C$ -3 Q2 $V_{GS} = 4.5 V$, $I_D = 3.0 A$ $R_{\text{DS(on)}}$ 50 70 Static Drain-Source Q1 mΩ $V_{GS} = 2.5 V$, $I_D = 2.5 A$ 95 66 **On-Resistance** $V_{GS} = 4.5 \text{ V}, I_D = 3.0 \text{ A}, T_J = 125^{\circ}\text{C}$ 106 71 $V_{GS} = -4.5 \text{ V}, I_D = -2.2 \text{ A}$ 125 100 Q2 $V_{GS} = -2.5 \text{ V}, I_D = -1.8 \text{ A}$ 190 145 $V_{GS} = -4.5 V, I_D = -2.2 A, T_J = 125^{\circ}C$ 184 137 $V_{\text{GS}} = 4.5 \text{ V}, \quad V_{\text{DS}} = 5 \text{ V}$ **On–State Drain Current** А Q1 12 I_{D(on)} $V_{GS} = -4.5 V, V_{DS} = -5 V$ Q2 -6 $V_{DS} = 5 V$ $I_{D} = 2.5 \text{ A}$ Forward Transconductance 10 S Q1 **g**_{FS} $V_{DS} = -5 V$ Q2 $I_{D} = -2.0A$ 6 **Dynamic Characteristics** V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz C_{iss} Input Capacitance Q1 324 pF Q2 V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz 337 V_{DS} =10 V, V _{GS}= 0 V, f=1.0MHz Coss **Output Capacitance** Q1 82 pF V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz Q2 88 C_{rss} **Reverse Transfer Capacitance** V_{DS}=10 V, V_{GS}= 0 V, f=1.0MHz 42 pF Q1 V_{DS}=-10 V, V_{GS}= 0 V, f=1.0MHz Q2 51 Switching Characteristics (Note 2) Turn-On Delay Time 5 10 t_{d(on)} Q1 For Q1: ns $V_{\text{DS}} = 10 \text{ V},$ $I_{DS}=1$ A Q2 9 18 V_{GS} = 4.5 V, R_{GEN} = 6 Ω t, Turn-On Rise Time Q1 7 14 ns Q2 For **Q2**: 12 22 $V_{DS} = -10 V$, $I_{DS} = -1 A$ Turn-Off Delay Time 13 23 Q1 t_{d(off)} ns V_{GS} = -4.5 V, R_{GEN} = 6 Ω 10 20 Q2 Turn-Off Fall Time 1.6 3 tf Q1 ns Q2 5 10 Qg 3.3 4.6 **Total Gate Charge** Q1 nC For Q1: $V_{DS} = 10 V$, 3.7 I_{DS}= 3.0 A Q2 $V_{GS} = 4.5 V$, 0.95 Q_{gs} Gate-Source Charge Q1 nC For **Q2**: 0.68 Q2 $V_{DS} = -10 \text{ V}, \text{ I}_{DS} = -2.2 \text{ A}$ Q_{gd} Gate-Drain Charge Q1 0.7 nC $V_{GS} = -4.5 V$, Q2 1.3

FDC6420C

FDC6420C Rev C(W)

-			8					
Symbol	Parameter		Test Conditions	Min	Тур	Max	Units	
Drain-S	ource Diode Characterist	tics a	nd Maximum Ratings					
1	Maria Oralia Daria Or	is de Fernuerd Ourrent	01			0.0	А	
Is	Maximum Continuous Drain–So	Durce L	node Forward Current	Q1			0.8	A
IS	Maximum Continuous Drain-Sc	burce L	node Forward Current	Q2			-0.8	A
V _{SD}	Drain–Source Diode Forward	Q1				0.7		A

Notes:

1. R_{6JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{6JC} is guaranteed by design while R_{6CA} is determined by the user's board design.



a) 130 °C/W when mounted on a 0.125 in² pad of 2 oz. copper.



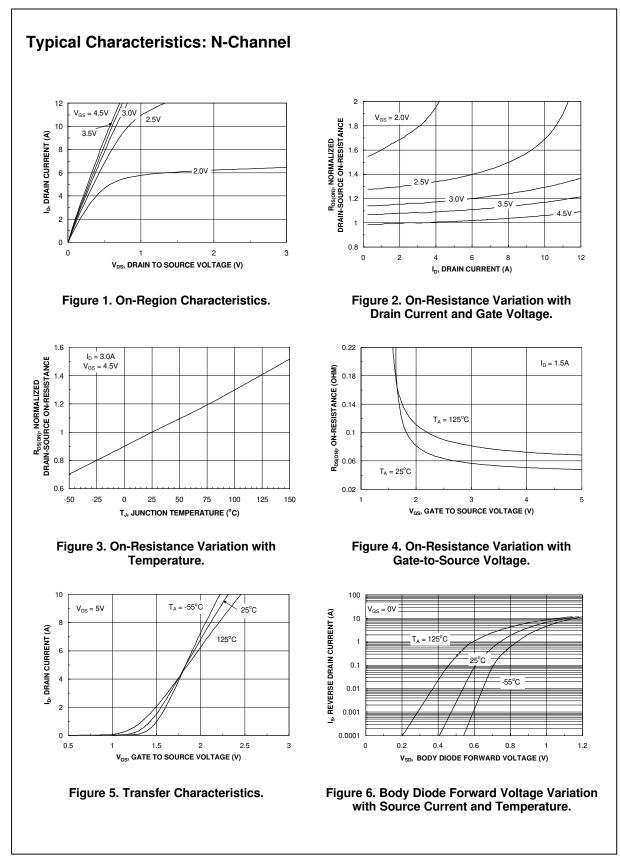
b) 140 °C/W when mounted on a .004 in² pad of 2 oz copper

c) 180 C°/W when mounted on a minimum pad.

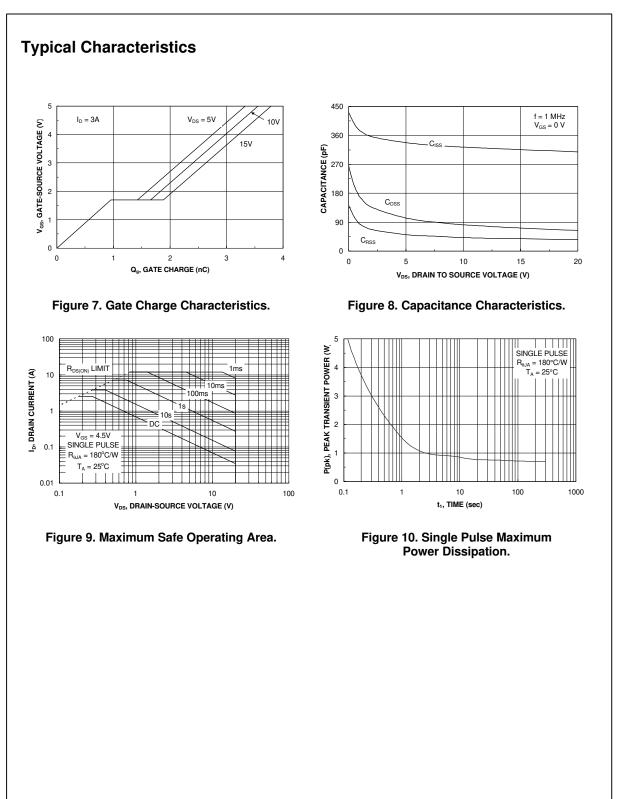
FDC6420C

Scale 1 : 1 on letter size paper

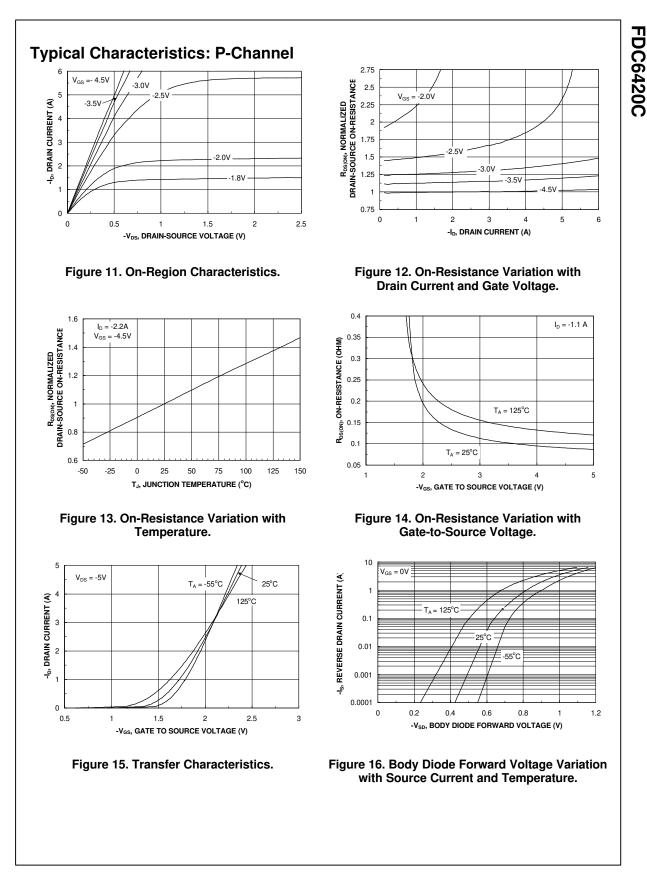
2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%



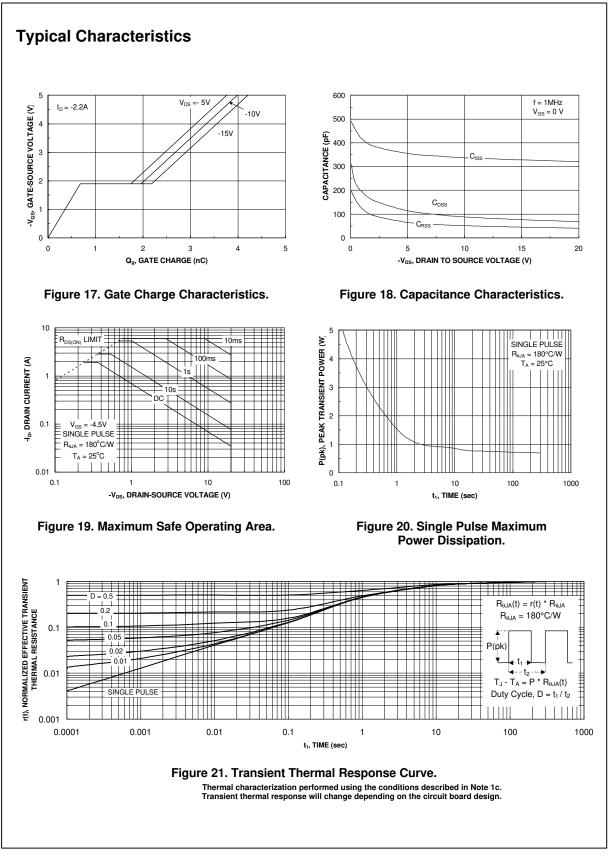
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